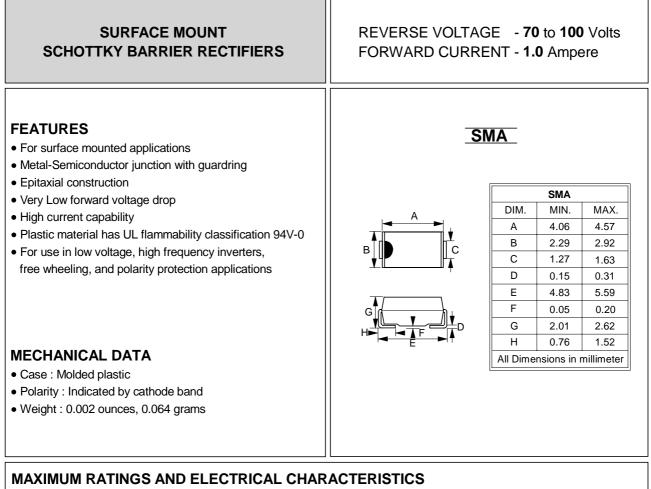
## LITE ON SEMICONDUCTOR

## B170 thru B1100



Ratings at  $25^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	B170	B180	B190	B1100	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	70	80	90	100	V
Maximum RMS Voltage	VRMS	49	56	63	70	V
Maximum DC Blocking Voltage	VDC	70	80	90	100	V
Maximum Average Forward Rectified Current @TL=100°C	I(AV)	1.0				A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD)	IFSM	30				A
Maximum forward@TJ =25°CVoltage at 1.0A DC@TJ =100°C	VF	0.79 0.69				v
Maximum DC Reverse Current@TJ =25°Cat Rated DC Blocking Voltage@TJ =100°C	IR	0.5 5.0				mA
Typical Junction Capacitance (Note 1)	Cı	30				pF
Typical Thermal Resistance (Note 2)	Rejl	25				°C/W
Operating Temperature Range	TJ	-55 to +125				°C
Storage Temperature Range	TSTG	-55 to +150				°C
NOTES 1 Measured at 1 0MHz and applied re	verse voltag			DEV	2 01 Dec 2000	Kenvo

NOTES : 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC. 2.Thermal Resistance Junction to Lead. REV. 2, 01-Dec-2000, KSHA02

## RATING AND CHARACTERISTIC CURVES B170 thru B1100

## FIG.1 - FORWARD CURRENT DERATING CURVE FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT PEAK FORWARD SURGE CURRENT, AMPERES 1.0 30 AVERAGE FORWARD CURRENT AMPERES 0.8 20 0.6 0.4 10 0.2 Pulse Width 8.3ms SINGLE PHASE HALF WAVE 60Hz RESISTIVE OR INDUCTIVE LOAD Single Half-Sine-Wave (JEDEC METHOD) 0 0 20 40 60 80 90 100 120 140 2 5 10 20 50 100 1 LEAD TEMPERATURE ,°C NUMBER OF CYCLES AT 60Hz FIG.3 - TYPICAL FORWARD CHARACTERISTICS FIG.4 - TYPICAL JUNCTION CAPACITANCE 1000 10 INSTANTANEOUS FORWARD CURRENT, (A) CAPACITANCE, (pF) 1.0 100 ++++ 0.1 -TJ = 25°C PULSEWIDTH: 300us TJ = 25°C F= 1MHz .01 10 0.1 100 0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 1.0 4.0 10.0 INSTANTANEOUS FORWARD VOLTAGE, (VOLTS) **REVERSE VOLTAGE**, (VOLTS) FIG.5 - TYPICAL REVERSE CHARACTERISTICS 100 INSTANTANEOUS REVERSE CURRENT, (mA) 10 . TJ = 125°C 1.0 TJ = 100°C 0.1 TJ = 25°( 0.01 0.001 40 120 140 0 20 60 80 90 100 PERCENT OF RATED PEAK REVERSE VOLTAGE, (%)

LITEON